

FEATURES

- Ø 1.13 mm active area
- Long term stability
- High sensitivity
- UV/ Blue enhanced

DESCRIPTION

1.0 mm² UV Silicon Photodiode with N on P construction. Hermetically packaged in a TO-52 with a UV transmitting clear glass window cap.

APPLICATIONS

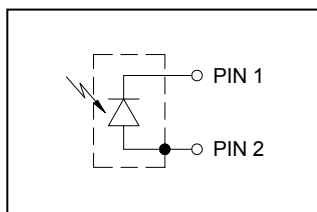
- UV exposure meters
- Pollution monitoring
- Fluorescent analyzers
- Medical instrumentation



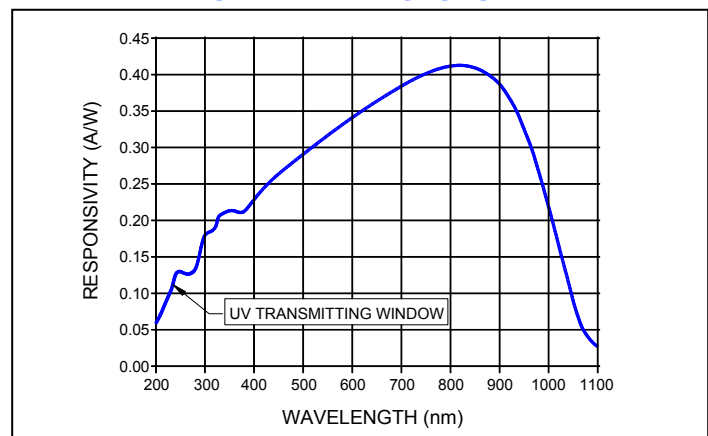
ABSOLUTE MAXIMUM RATING

SYMBOL	PARAMETER	MIN	MAX	UNITS
T _{STG}	Storage Temp	-55	+125	°C
T _{OP}	Operating Temp	-40	+100	°C
V _{R(OP)}	Reverse Operating Voltage	-	50	V
I _(PEAK)	Peak DC Current	-	10	mA

SCHEMATIC



SPECTRAL RESPONSE



ELECTRO-OPTICAL CHARACTERISTICS @ 22° C

SYMBOL	CHARACTERISTIC	TEST CONDITIONS	MIN	TYP	MAX	UNITS
R _{SH}	Shunt Resistance	V _R = ±10 mV	500	2000	---	MΩ
I _D	Dark Current	V _R = 5 V	---	0.2	---	nA
C	Capacitance	V _R = 0 V	---	60	---	pF
		V _R = 5 V	---	30	---	
	Responsivity	V _R = 0 V; λ = 340 nm	---	0.17	---	A/W
		V _R = 0 V; λ = 850 nm	---	0.42	---	
NEP	Noise Equivalent Power	V _R = 0 V; λ = 850 nm; R _L = 50 Ω	---	8.0 X 10 ⁻¹⁵	---	W/Hz ^{1/2}
V _{BR}	Breakdown Voltage	I _R = 10 μA	30	50	---	V
t _r	Rise Time	V _R = 5 V; λ = 410 nm; R _L = 50 Ω	---	0.1	---	μs

These devices are sensitive to electrostatic discharge. Please use ESD precautions when handling.

Disclaimer: Due to our policy of continued development, specifications are subject to change without notice.

USA:

Pacific Silicon Sensor, Inc.
5700 Corsa Avenue, #105
Westlake Village, CA 91362 USA
Phone (818) 706-3400
Fax (818) 889-7053
Email: sales@pacific-sensor.com
www.pacific-sensor.com

7/7/2010

International sales:

Silicon Sensor International AG
Peter-Behrens-Str. 15
D-12459 Berlin, Germany
Phone +49 (0)30-63 99 23 10
Fax +49 (0)30-63 99 23 33
Email: sales@silicon-sensor.de
www.silicon-sensor.de